imall

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Taiwan Semiconductor

Dual Common Cathode Schottky Rectifier

FEATURES

- Low power loss, high efficiency
- Guardring for overvoltage protection
- High surge current capability
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition

MECHANICAL DATA

Case: TO-220AB

Molding compound, UL flammability classification rating 94V-0

Base P/N with suffix "G" on packing code - halogen-free

Base P/N with prefix "H" on packing code - AEC-Q101 qualified

Terminal: Matte tin plated leads, solderable per JESD22-B102

Meet JESD 201 class 1A whisker test,

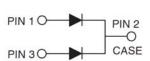
with prefix "H" on packing code meet JESD 201 class 2 whisker test Polarity: As marked

Mounting torque: 5 in-lbs maximum

Weight: 1.88 a (approximately)



TO-220AB



		MBR	MBR	MBR	MBR	MBR	MBR	MBR	MBR	
PARAMETER	SYMBOL	2035	2045	2050	2060	2090	20100	20150	20200	UNIT
		СТ	СТ	СТ	СТ	ст	СТ	СТ	СТ	
Maximum repetitive peak reverse voltage	V _{RRM}	35	45	50	60	90	100	150	200	V
Maximum RMS voltage	V _{RMS}	24	31	35	42	63	70	105	140	V
Maximum DC blocking voltage	V _{DC}	35	45	50	60	90	100	150	200	V
Maximum average forward rectified current	I _{F(AV)}				2	20	•		•	Α
Peak repetitive forward current (Rated VR, Square Wave, 20KHz)	I _{FRM}	20					A			
Peak forward surge current, 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	150					А			
Peak repetitive reverse surge current (Note 1)	I _{RRM}	1 0.5				А				
Maximum instantaneous forward voltage (Note 2) $I_{\text{F}}\text{=}10\text{A},T_{\text{J}}\text{=}25^{\circ}\!\!\!\!\!\!\mathrm{C}$			-	0.	80	0.	85	0.	99	
I _F =10A, T _J =125℃	V_{F}	0.	57	0.	70	0.	75	0.	87	V
I _F =20A, T _J =25℃		0.	84	0.	95	0.	95	1.	23	
I _F =20A, T _J =125℃		0.72 0.85		0.	85 1.10		10			
Maximum reverse current @ rated VR T_J =25 $^\circ\!C$		0.1								
T 」=125 ℃	I _R	1	5	10		5			0.15	mA
Voltage rate of change (Rated V _R)	dV/dt	10000				V/µs				
Typical thermal resistance	R _{θJC}	1.0 2.0			^o C/W					
Operating junction temperature range	TJ	- 55 to +150			OO					
Storage temperature range	T _{STG}	- 55 to +150				°C				

Note 2: Pulse test with PW=300µs, 1% duty cycle



MBR2035CT thru MBR20200CT

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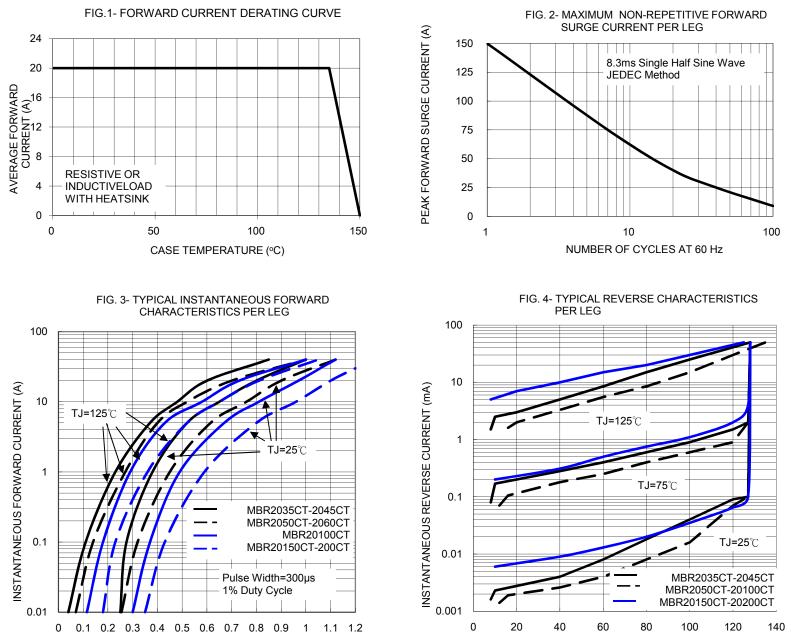
ORDERING INFORMATION						
PART NO.	AEC-Q101	PACKING CODE	GREEN COMPOUND	PACKAGE	PACKING	
	QUALIFIED	PACKING CODE	CODE	PACKAGE	FACKING	
MBR20xxCT	Prefix "H"	C0	Suffix "G"	TO-220AB	50 / Tube	
Note 1: "xx" defines voltage from 35V (MBR2035CT) to 200V (MBR20200CT)						

defines voltage from 35V (MBR2035C1) to 200V (MBR20200C1) 1:

EXAMPLE							
PREFERRED P/N	PART NO.	AEC-Q101 QUALIFIED	PACKING CODE	GREEN COMPOUND CODE	DESCRIPTION		
MBR2060CT C0	MBR2060CT		C0				
MBR2060CT C0G	MBR2060CT		C0	G	Green compound		
MBR2060CTHC0	MBR2060CT	Н	C0		AEC-Q101 qualified		

RATINGS AND CHARACTERISTICS CURVES

(TA=25°C unless otherwise noted)

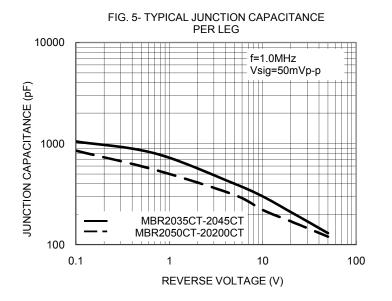


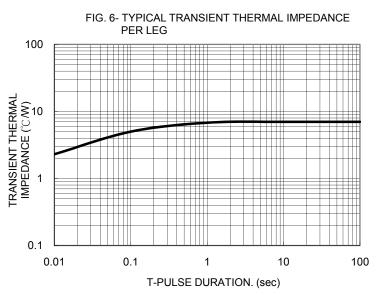
FORWARD VOLTAGE (V)

PERCENT OF RATED PEAK REVERSE VOLTAGE (%)

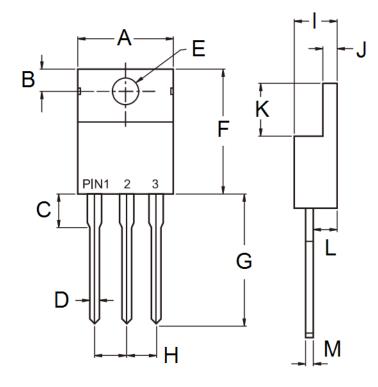


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PACKAGE OUTLINE DIMENSIONS



DIM.	Unit	(mm)	Unit (inch)		
	Min	Max	Min	Max	
А	-	10.50	-	0.413	
В	2.62	3.44	0.103	0.135	
С	2.80	4.20	0.110	0.165	
D	0.68	0.94	0.027	0.037	
E	3.54	4.00	0.139	0.157	
F	14.60	16.00	0.575	0.630	
G	13.19	14.79	0.519	0.582	
Н	2.41	2.67	0.095	0.105	
I	4.42	4.76	0.174	0.187	
J	1.14	1.40	0.045	0.055	
К	5.84	6.86	0.230	0.270	
L	2.20	2.80	0.087	0.110	
М	0.35	0.64	0.014	0.025	

MARKING DIAGRAM



- = Marking Code
- = Green Compound
- = Date Code
 - = Factory Code



Taiwan Semiconductor

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